# W78E65/W78E065A Data Sheet



# **8-BIT MICROCONTROLLER**

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# 1. GENERAL DESCRIPTION

The W78E65 is an 8-bit microcontroller which has an in-system programmable Flash EPROM for firmware updating. The instruction set of the W78E65 is fully compatible with the standard 8052. The W78E65 contains a 64K bytes of main ROM and a 4K bytes of auxiliary ROM which allows the contents of the 64KB main ROM to be updated by the loader program located at the 4KB auxiliary ROM; 256+1K bytes of on-chip RAM; four 8-bit bi-directional and bit-addressable I/O ports; an additional 4-bit port P4; three 16-bit timer/counters; a serial port. These peripherals are supported by a eight sources two-level interrupt capability. To facilitate programming and verification, the ROM inside the W78E65 allows the program memory to be programmed and read electronically. Once the code is confirmed, the user can protect the code for security.

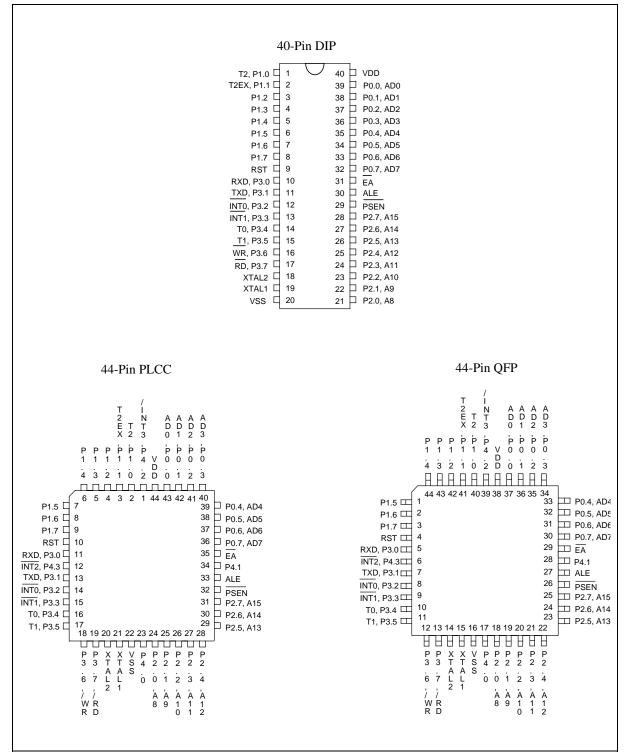
The W78E65 microcontroller has two power reduction modes, idle mode and power-down mode, both of which are software selectable. The idle mode turns off the processor clock but allows for continued peripheral operation. The power-down mode stops the crystal oscillator for minimum power consumption. The external clock can be stopped at any time and in any state without affecting the processor.

# 2. FEATURES

- Fully static design 8-bit CMOS microcontroller
- 64K bytes of in-system programmable Flash EPROM for Application Program (AP FLASH EPROM)
- 4K bytes of auxiliary ROM for Loader Program (LD FLASH EPROM)
- 256+1K bytes of on-chip RAM. (Including 1K bytes of AUX-RAM, software selectable)
- 64K bytes program memory address space and 64K bytes data memory address space
- ALE off software selectable.
- Four 8-bit bi-directional ports; Port 0 has internal pull-up resisters enabled by software
- One 4-bit multipurpose programmable port (I/O, interrupt, Chip select function)
- Three 16-bit timer/counters
- One full duplex serial port
- 5 channel PWM
- Watchdog timer
- Software Reset
- P1.0 T2 programmable clock out
- Eight-sources, two-level interrupt capability
- Built-in power management
- Code protection
- Packaged in
  - DIP 44: W78E65-40
  - PLCC 44: W78E65P-40
  - QFP 44: W78E65F-40
  - Lead Free(RoHS) PLCC 44: W78E065A40PL
  - Lead Free(RoHS) DIP 40: W78E065A40DL
  - Lead Free(RoHS) QFP 44: W78E065A40FL



# 3. PIN CONFIGURATIONS





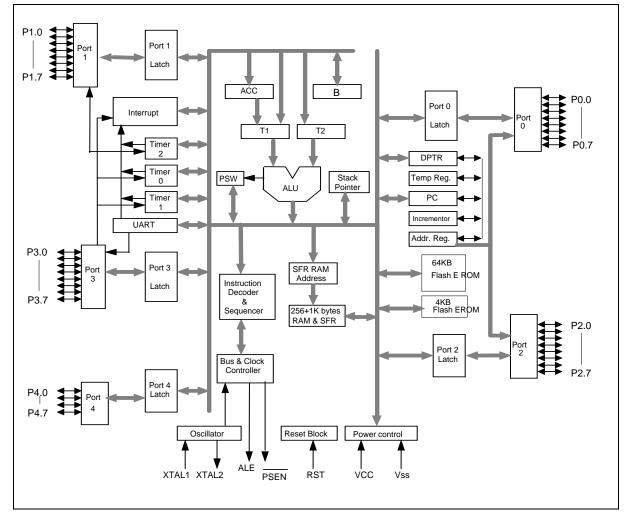
# 4. PIN DESCRIPTION

SYMBOL	TYPE	DESCRIPTIONS
EA	I	EXTERNAL ACCESS ENABLE: This pin forces the processor to execute the external ROM. The ROM address and data will not be presented on the bus if the $\overline{EA}$ pin is high.
PSEN	ОН	PROGRAM STORE ENABLE: PSEN enables the external ROM data in the Port 0 address/data bus. When internal ROM access is performed, no PSEN strobe signal outputs originate from this pin.
ALE	ОН	ADDRESS LATCH ENABLE: ALE is used to enable the address latch that separates the address from the data on Port 0. ALE runs at 1/6th of the oscillator frequency.
RST	ΙL	RESET: A high on this pin for two machine cycles while the oscillator is running resets the device.
XTAL1	I	CRYSTAL 1: This is the crystal oscillator input. This pin may be driven by an external clock.
XTAL2	0	CRYSTAL 2: This is the crystal oscillator output. It is the inversion of XTAL1.
Vss	Ι	GROUND: ground potential.
Vdd	I	POWER SUPPLY: Supply voltage for operation.
P0.0-P0.7	I/O D	PORT 0: Function is the same as that of standard 8052. This port also provides a multiplexed low order address/data bus during accesses to external memory. Port 0 has internal pull-up resisters enabled by software.
P1.0-P1.7	I/O H	PORT 1: Function is the same as that of standard 8052.
P2.0-P2.7	I/O H	PORT 2: Port 2 is a bi-directional I/O port with internal pull-ups. This port also provides the upper address bits for accesses to external memory. The P2.6 and P2.7 also provide the alternate function $\overrightarrow{REBOOT}$ which is H/W reboot from LD flash.
P3.0-P3.7	I/O H	PORT 3: Function is the same as that of the standard 8052.
P4.0-P4.3	I/O H	$\begin{array}{l} \mbox{PORT 4: A bi-directional I/O. The P4.3 also provide the alternate function} \\ \hline \mbox{REBOOT} & \mbox{which is H/W reboot from LD flash.} \end{array}$

\* Note: TYPE I: input, O: output, I/O: bi-directional, H: pull-high, L: pull-low, D: open drain



# 5. BLOCK DIAGRAM





# 6. FUNCTIONAL DESCRIPTION

The W78E65 architecture consists of a core controller surrounded by various registers, four general purpose I/O ports, one special purpose programmable 4-bits I/O port, 256+1K bytes of RAM, three timer/counters, a serial port. The processor supports 111 different opcodes and references both a 64K program address space and a 64K data storage space.

# 6.1 RAM

The internal data RAM in the W78E65 is 256+1K bytes. It is divided into two banks: 256 bytes of scratchpad RAM and 1K bytes of AUX-RAM. These RAMs are addressed by different ways.

- RAM 0H–7FH can be addressed directly and indirectly as the same as in 8051. Address pointers are R0 and R1 of the selected register bank.
- RAM 80H–FFH can only be addressed indirectly as the same as in 8051. Address pointers are R0, R1 of the selected registers bank.
- AUX-RAM 0H–3FFH is addressed indirectly as the same way to access external data memory with the MOVX instruction. Address pointer are R0 and R1 of the selected register bank and DPTR register. An access to external data memory locations higher than 3FFH will be performed with the MOVX instruction in the same way as in the 8051. The AUX-RAM is enable after a reset. Setting the bit 4 in CHPCON register will enable the access to AUX-RAM. When executing from internal program memory, an access to AUX-RAM will not affect the Ports P0, P2, WR and RD.

Example,

CHPENI CHPCOI XRAMAI	N REG	F6H BFH A1H	
MOV	CHPENR, #	#87H	
MOV	CHPENR, #	#59H	
ORL	CHPCON,	#00010000B	; enable AUX-RAM
MOV	CHPENR, #	#00H	
MOV	XRAMAH, #	#01H	; internal high address
MOV	R0, #23H		
MOV	A, #55H		
MOVX	@R0, A		; Write 55h data to 0123h AUX-RAM address.
MOV	XRAMAH, #	#02H	
MOV	R1, #FFH		; Read data from 02FFh AUX-RAM address.
MOVX	A, @R1		
MOV	DPTR, #0134H		
MOV	A, #78H		
MOVX	@DPTR, /	4	; Write 78h data to 0134h AUX-RAM address.
MOV	DPTR, #7F	FFH	
MOVX	A, @DPR	Г	; Read data from the external 7FFFh address SRAM



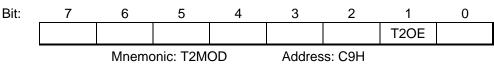
### 6.2 Timers 0, 1, and 2

Timers 0, 1, and 2 each consist of two 8-bit data registers. These are called TL0 and TH0 for Timer 0, TL1 and TH1 for Timer 1, and TL2 and TH2 for Timer 2. The TCON and TMOD registers provide control functions for timers 0, 1. The T2CON register provides control functions for Timer 2. RCAP2H and RCAP2L are used as reload/capture registers for Timer 2. The operations of Timer 0 and Timer 1 are the same as in the W78C51. Timer 2 is a 16-bit timer/counter that is configured and controlled by the T2CON register. Like Timers 0 and 1, Timer 2 can operate as either an external event counter or as an internal timer, depending on the setting of bit C/T2 in T2CON. Timer 2 has three operating modes: capture, auto-reload, and baud rate generator. The clock speed at capture or auto-reload mode is the same as that of Timers 0 and 1.

### 6.2.1 Timer 2 Output

If Set T2OE(T2MOD.1) bit and clear C/T2 (T2CON.1) bit when CPU work at auto-reload mode and happen overflow, CPU will toggle P1.0 pin.

TIMER 2 Mode



T2OE: Enable this bit to toggle P1.0 pin while Timer2 has been overflowed.

### 6.3 Clock

The W78E65 is designed with either a crystal oscillator or an external clock. Internally, the clock is divided by two before it is used by default. This makes the W78E65 relatively insensitive to duty cycle variations in the clock.

#### 6.3.1 Crystal Oscillator

The W78E65 incorporates a built-in crystal oscillator. To make the oscillator work, a crystal must be connected across pins XTAL1 and XTAL2. In addition, a load capacitor must be connected from each pin to ground.

#### 6.3.2 External Clock

An external clock should be connected to pin XTAL1. Pin XTAL2 should be left unconnected. The XTAL1 input is a CMOS-type input, as required by the crystal oscillator.

### 6.4 Power Management

#### 6.4.1 Idle Mode

Setting the IDL bit in the PCON register enters the idle mode. In the idle mode, the internal clock to the processor is stopped. The peripherals and the interrupt logic continue to be clocked. The processor will exit idle mode when either an interrupt or a reset occurs.



### 6.4.2 Power-down Mode

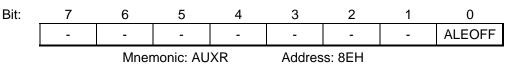
When the PD bit in the PCON register is set, the processor enters the power-down mode. In this mode all of the clocks are stopped, including the oscillator. To exit from power-down mode is by a hardware reset or external interrupts INTO to INT1 when enabled and set to level triggered.

### 6.4.3 Reduce EMI Emission

The W78E65 allows user to diminish the gain of on-chip oscillator amplifier by using programmer to clear the B7 bit of security register. Once B7 is set to 0, a half of gain will be decreased. Care must be taken if user attempts to diminish the gain of oscillator amplifier, reducing a half of gain may affect the external crystal operating improperly at high frequency. The value of C1 and C2 may need some adjustment while running at lower gain.

#### **ALE OFF Function**

Auxiliary Register



ALEOFF: Set this bit to disable ALE output.

### 6.5 Reset

The external RESET signal is sampled at S5P2. To take effect, it must be held high for at least two machine cycles while the oscillator is running. An internal trigger circuit in the reset line is used to deglitch the reset line when the W78E65 is used with an external RC network. The reset logic also has a special glitch removal circuit that ignores glitches on the reset line. During reset, the ports are initialized to FFH, the stack pointer to 07H, PCON (with the exception of bit 4) to 00H, and all of the other SFR registers except SBUF to 00H. SBUF is not reset.



F8									FF
F0	+B 00000000						CHPENR 00000000		F7
E8									EF
E0	+ACC 00000000								E7
D8	+P4 11111111	PWMP 00000000	PWM0 00000000	PWM1 00000000	PWMCON1 00000000	PWM2 00000000	PWM3 00000000		DF
D0	+PSW 00000000								D7
C8	+T2CON 00000000	T2MOD 00000000	RCAP2L 00000000	RCAP2H 00000000	TL2 00000000	TH2 00000000	PWMCON 2 00000000	PWM4 00000000	CF
C0	+XICON 00000000		P4CONA 00000000	P4CONB 00000000	SFRAL 00000000	SFRAH 00000000	SFRFD 00000000	SFRCN 00000000	C7
B8	+IP 00000000							CHPCON 0xx00000	BF
B0	+P3 00000000				P43AL 00000000	P43AH 00000000			B7
A8	+IE 00000000				P42AL 00000000	P42AH 00000000	P4CSIN 00000000		AF
A0	+P2 11111111	XRAMAH 00000000							A7
98	+SCON 00000000	SBUF xxxxxxxx							9F
90	+P1 11111111				P41AL 00000000	P41AH 00000000			97
88	+TCON 00000000	TMOD 00000000	TL0 00000000	TL1 00000000	TH0 00000000	TH1 00000000	AUXR 00000000	WDTC 00000000	8F
80	+P0 11111111	SP 00000111	DPL 00000000	DPH 00000000	P40AL 00000000	P40AH 00000000	POR 00000000	PCON 00110000	87

# 6.5.1 W78E65 Special Function Registers (SFRs) and Reset Values

Notes:

1. The SFRs marked with a plus sign(+) are both byte- and bit-addressable.

2. The text of SFR with bold type characters are extension function registers.



# 6.6 Port 4

Port 4, address D8H, is a 8-bit multipurpose programmable I/O port. Each bit can be configured individually by software. The Port 4 has four different operation modes.

- Mode 0: P4.0–P4.3 is a bi-directional I/O port which is same as port 1. P4.2 and P4.3 also serve as external interrupt INT3 and INT2 if enabled.
- Mode 1: P4.0–P4.3 are read strobe signals that are synchronized with RD signal at specified addresses. These signals can be used as chip-select signals for external peripherals.
- Mode 2: P4.0–P4.3 are write strobe signals that are synchronized with WR signal at specified addresses. These signals can be used as chip-select signals for external peripherals.
- Mode 3: P4.0–P4.3 are read/write strobe signals that are synchronized with RD or WR signal at specified addresses. These signals can be used as chip-select signals for external peripherals.

When Port 4 is configured with the feature of chip-select signals, the chip-select signal address range depends on the contents of the SFR P4xAH, P4xAL, P4CONA and P4CONB. The registers P4xAH and P4xAL contain the 16-bit base address of P4.x. The registers P4CONA and P4CONB contain the control bits to configure the Port 4 operation mode.

#### 6.6.1 Port Options Register



P0UP: Enable Port 0 weak up. The pins of Port 0 can be configured with either the open drain or standard port with internal pull-up. By the default, Port 0 is an open drain bi-directional I/O port. When the P0UP bit in the POR register is set, the pins of port 0 will perform a bi-directional I/O port with internal pull-up that is structurally the same Port2.

### 6.6.2 INT2 / INT3

Two additional external interrupts,  $\overline{INT2}$  and  $\overline{INT3}$ , whose functions are similar to those of external interrupt 0 and 1 in the standard 80C52. The functions/status of these interrupts are determined/shown by the bits in the XICON (External Interrupt Control) register. The XICON register is bit-addressable but is not a standard register in the standard 80C52. Its address is at 0C0H. To set/clear bits in the XICON register, one can use the "SETB ( $\overline{CLR}$ ) bit" instruction. For example, "SETB 0C2H" sets the EX2 bit of XICON.

XICON - external interrupt control (C0H)

PX3 EX3 IE3 IT3 PX2 EX2 IE2 IT2
---------------------------------

PX3: External interrupt 3 priority high if set

EX3: External interrupt 3 enable if set

IE3: If IT3 = 1, IE3 is set/cleared automatically by hardware when interrupt is detected/serviced

# 

IT3: External interrupt 3 is falling-edge/low-level triggered when this bit is set/cleared by software

PX2: External interrupt 2 priority high if set

EX2: External interrupt 2 enable if set

IE2: If IT2 = 1, IE2 is set/cleared automatically by hardware when interrupt is detected/serviced

IT2: External interrupt 2 is falling-edge/low-level triggered when this bit is set/cleared by software

#### POLLING ENABLE INTERRUPT VECTOR **INTERRUPT SOURCE** SEQUENCE WITHIN REQUIRED TYPE ADDRESS PRIORITY LEVEL SETTINGS EDGE/LEVEL External Interrupt 0 03H 0 (highest) IE.0 TCON.0 Timer/Counter 0 0BH IE.1 1 -**External Interrupt 1** 13H 2 IE.2 TCON.2 Timer/Counter 1 1BH 3 IE.3 -Serial Port 4 IE.4 23H -Timer/Counter 2 5 IE.5 2BH -33H 6 XICON.2 XICON.0 **External Interrupt 2 External Interrupt 3** 3BH 7 (lowest) XICON.6 XICON.3

### **Eight-source interrupt information:**

# P4CONB (C3H)

BIT	NAME	FUNCTION
7, 6	P43FUN1 P43FUN0	<ul> <li>00: Mode 0. P4.3 is a general purpose I/O port which is the same as Port1.</li> <li>01: Mode 1. P4.3 is a Read Strobe signal for chip select purpose. The address range depends on the SFR P43AH, P43AL, P43CMP1 and P43CMP0.</li> <li>10: Mode 2. P4.3 is a Write Strobe signal for chip select purpose. The address range depends on the SFR P43AH, P43AL, P43CMP1 and P43CMP0.</li> <li>11: Mode 3. P4.3 is a Read/Write Strobe signal for chip select purpose. The address range depends on the SFR P43AH, P43AL, P43CMP1 and P43CMP0.</li> </ul>
5, 4	P43CMP1 P43CMP0	<ul> <li>P43CMP0.</li> <li>Chip-select signals address comparison:</li> <li>00: Compare the full address (16 bits length) with the base address register P43AH, P43AL.</li> <li>01: Compare the 15 high bits (A15–A1) of address bus with the base address register P43AH, P43AL.</li> <li>10: Compare the 14 high bits (A15–A2) of address bus with the base address register P43AH, P43AL.</li> <li>11: Compare the 8 high bits (A15–A8) of address bus with the base address register P43AH, P43AL.</li> </ul>



#### P4CONB (C3H), continued

BIT	NAME	FUNCTION
3, 2	P42FUN1	The P4.2 function control bits which are the similar definition as P43FUN1,
	P42FUN0	P43FUN0.
1, 0	P42CMP1	The P4.2 address comparator length control bits which are the similar
	P42CMP0	definition as P43CMP1, P43CMP0.

#### P4CONA (C2H)

BIT	NAME	FUNCTION
7,6	P41FUN1	The P4.1 function control bits which are the similar definition as P43FUN1,
., 0	P41FUN0	P43FUN0.
5, 4	P41CMP1	The P4.1 address comparator length control bits which are the similar
	P41CMP0	definition as P43CMP1, P43CMP0.
3, 2	P40FUN1	The P4.0 function control bits which are the similar definition as P43FUN1,
3, Z	P40FUN0	P43FUN0.
1, 0	P40CMP1	The P4.0 address comparator length control bits which are the similar
	P40CMP0	definition as P43CMP1, P43CMP0.

#### P4CSIN (AEH)

BIT	NAME	FUNCTION
7	P43CSINV	The active polarity of P4.3 when pin P4.3 is defined as read and/or write strobe signal. = 1: P4.3 is active high when pin P4.3 is defined as read and/or write strobe signal.
		= 0: P4.3 is active low when pin P4.3 is defined as read and/or write strobe signal.
6	P42CSINV	The similarity definition as P43SINV.
5	P41CSINV	The similarity definition as P43SINV.
4	P40CSINV	The similarity definition as P43SINV.
3	-	Reserve
2	-	Reserve
1	-	0
0	-	0

#### 6.6.3 Port 4 Base Address Registers

#### P40AH, P40AL:

The Base address register for comparator of P4.0. P40AH contains the high-order byte of address, P40AL contains the low-order byte of address.

#### P41AH, P41AL:

The Base address register for comparator of P4.1. P41AH contains the high-order byte of address, P41AL contains the low-order byte of address.



### P42AH, P42AL:

The Base address register for comparator of P4.2. P42AH contains the high-order byte of address, P42AL contains the low-order byte of address.

#### P43AH, P43AL:

The Base address register for comparator of P4.3. P43AH contains the high-order byte of address, P43AL contains the low-order byte of address.

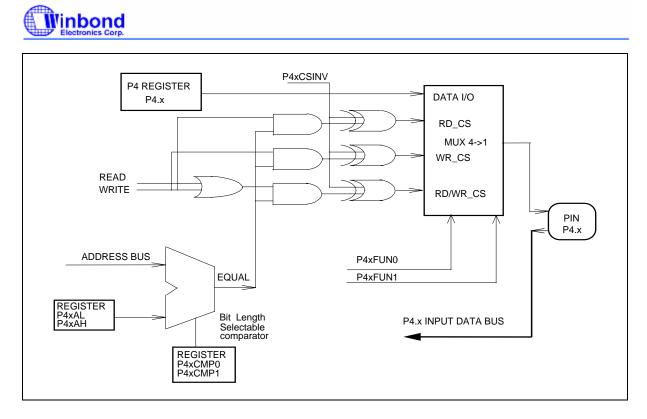
BIT	NAME	FUNCTION
7	P47	I/O pin
6	P46	I/O pin.
5	P45	I/O pin.
4	P44	I/O pin.
3	P43	Port 4 Data bit which outputs to pin P4.3 at mode 0.
2	P42	Port 4 Data bit. which outputs to pin P4.2 at mode 0.
1	P41	Port 4 Data bit. which outputs to pin P4.1at mode 0.
0	P40	Port 4 Data bit which outputs to pin P4.0 at mode 0.

#### P4 (D8H)

Here is an example to program the P4.0 as a write strobe signal at the I/O port address 1234H–1237H and positive polarity, and P4.1–P4.3 are used as general I/O ports.

MOV P40AH, #12H	
MOV P40AL, #34H	; Base I/O address 1234H for P4.0
MOV P4CONA, #00001010B	; P4.0 a write strobe signal and address line A0 and A1 are masked.
MOV P4CONB, #00H	; P4.1–P4.3 as general I/O port which are the same as PORT1
MOV P2ECON, #10H	; Write the P40SINV = 1 to inverse the P4.0 write strobe polarity
	; default is negative.

Then any instruction MOVX @DPTR, A (with DPTR = 1234H–1237H) will generate the positive polarity write strobe signal at pin P4.0. And the instruction MOV P4, #XX will output the bit3 to bit1 of data #XX to pin P4.3–P4.1.



# 6.7 Pulse Width Modulated Outputs (PWM)

There are five pulse width modulated output channels to generate pulses of programmable length and interval. The repedition frequency is defined by an 8-bit prescaler PWMP, which supplies the clock for the counter. The prescaler and counter are common to both PWM channels. The 8-bit counter counts modular 255 (0–254). The value of the 8-bit counteris compared to the contents of five registers: PWM0, PWM1, PWM2, PWM3 and PWM4. Provided the contents of either of these registers is greater than the counter value, the corresponding PWM0, PWM1, PWM2, PWM3 or PWM4 output is set HIGH. If the contents of these registers are equal to, or less than the counter value, the output will be LOW. The pulse-width-ratio is thesefore defined by the contents of the registers PWM0, PWM1, PWM2, PWM3 and PWM4. The pulse-width-ratio is in the range of 0 to 1 and may be programmed in increments of 1/255. ENPWM0, ENPWM1, ENPWM2, ENPWM3 and ENPWM4 bit will enable or disable PWM output.

Buffered PWM outputs may be used to drive DC motors. The rotation speed of the motor would be proportional to the contents of PWM0/1/2/3/4. The repetition frequency  $f_{pwm}$ , at the PWM0/1/2/3/4 output is given by:

 $f_{pwm} = \frac{f_{osc}}{2 \times (1 + PWMP) \times 255}$ Prescaler division factor = PWM + 1
PWMn high/low ratio of PWMn =  $\frac{(PWMn)}{255 - (PWMn)}$ 



This gives a repetition frequency range of 123 Hz to 31.4 KHz ( $f_{osc}$  = 16 MHz). By loading the PWM registers with either 00H or FFH, the PWM channels will output a constant HIGH or LOW level, respectively. Since the 8-bit counter counts modulo 255, it can never actually reach the value of the PWM registers when they are loaded with FFH.

When a compare register (PWM0, PWM1, PWM2, PWM3, PWM4) is loaded with a new value, the associated output updated immediately. It does not have to wait until the end of the current counter period. There is weakly pulled high on PWM output.

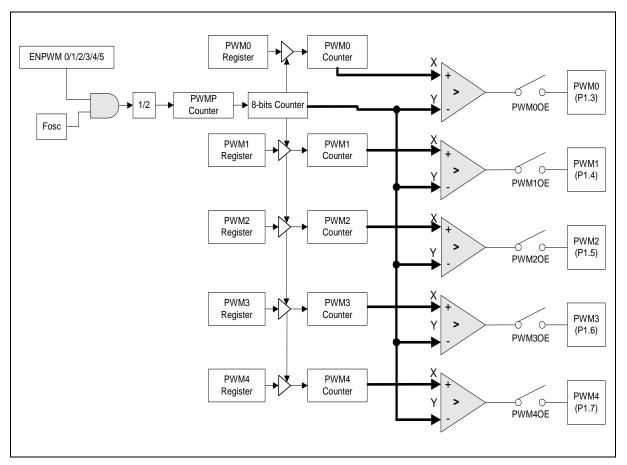


Figure 1 PWM diagram

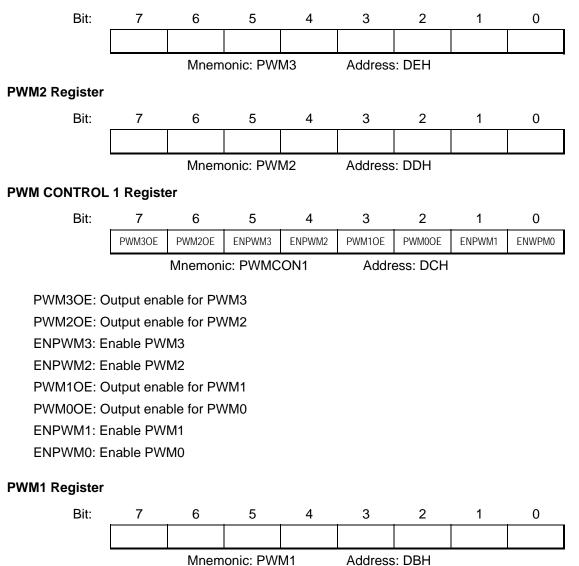
Please refer as below code.

mov pwmcon1, #00110011b ; enable pwm3, 2, 1, 0 pwmcon2, #00000101b ; enable pwm4 mov ; Fpwm =  $XT/(2^{(1+pwmp)^{255}})$ pwmp, #40h mov jb p1.3, \$ pwm0, #14h ; duty cycle high/low = pwm0/(255-pmw0)mov p1.4, \$ jb mov pwm1, #18h

# 

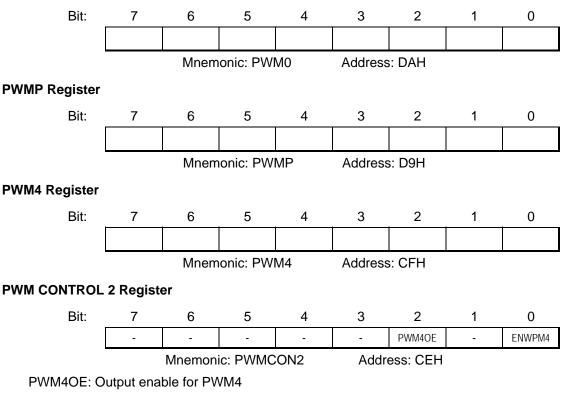
jb	p1.5, \$	
mov	pwm2, #20h	
jb	p1.6, \$	
mov	pwm3, #b0h	
jb	p1.7, \$	
mov	pwm4, #40h	
mov	pwmcon1, #11111111b	; output enable pwm3, 2, 1, 0

### **PWM3 Register**





#### **PWM0 Register**

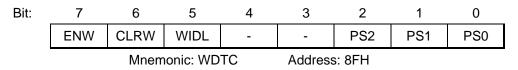


ENPWM: Enable for PWM4

### 6.8 Watchdog Timer

The Watchdog timer is a free-running timer which can be programmed by the user to serve as a system monitor, a time-base generator or an event timer. It is basically a set of dividers that divide the system clock. The divider output is selectable and determines the time-out interval. When the time-out occurs, a system reset can also be caused if it is enabled. The main use of the Watchdog timer is as a system monitor. This is important in real-time control applications. In case of power glitches or electromagnetic interference, the processor may begin to execute errant code. If this is left unchecked the entire system may crash. The watchdog time-out selection will result in different time-out values depending on the clock speed. The Watchdog timer will de disabled on reset. In general, software should restart the Watchdog timer to put it into a known state. The control bits that support the Watchdog timer are discussed below.

#### Watchdog Timer Control Register



ENW : Enable watch-dog if set.

CLRW: Clear watch-dog timer and prescaler if set. This flag will be cleared automatically



WIDL : If this bit is set, watch-dog is enabled under IDLE mode. If cleared, watch-dog is disabled under IDLE mode. Default is cleared.

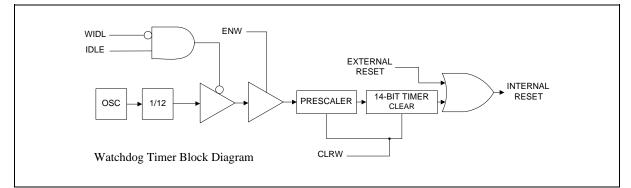
PS2, PS1, PS0: Watch-dog prescaler timer select. Prescaler is selected when set PS2–0 as follows:

PS2 PS1	PS0	PRESCALER SELECT
0 0	0	2
0 0	1	4
0 1	0	8
0 1	1	16
1 0	0	32
1 0	1	64
1 1	0	128
1 1	1	256

The time-out period is obtained using the following equation:

 $\frac{1}{OSC} \times 2^{14} \times \text{PRESCALER} \times 1000 \times 12 \text{ mS}$ 

Before Watchdog time-out occurs, the program must clear the 14-bit timer by writing 1 to WDTC.6 (CLRW). After 1 is written to this bit, the 14-bit timer, prescaler and this bit will be reset on the next instruction cycle. The Watchdog timer is cleared on reset.



Typical Watch-Dog time-out period when OSC = 20 MHz

PS2 PS1 PS0	WATCHDOG TIME-OUT PERIOD
0 0 0	19.66 mS
0 0 1	39.32 mS
0 1 0	78.64 mS
0 1 1	157.28 mS
1 0 0	314.57 mS
1 0 1	629.14 mS
1 1 0	1.25 S
1 1 1	2.50 S



# 6.9 In-System Programming (ISP) Mode

The W78E65 equips one 64K byte of main ROM bank for application program (called AP FLASH EPROM) and one 4K byte of auxiliary ROM bank for loader program (called LD FLASH EPROM). In the normal operation, the microcontroller executes the code in the AP FLASH EPROM. If the content of AP FLASH EPROM needs to be modified, the W78E65 allows user to activate the In-System Programming (ISP) mode by setting the CHPCON register. The CHPCON is read-only by default, software must write two specific values 87H, then 59H sequentially to the CHPENR register to enable the CHPCON write attribute. Writing CHPENR register with the values except 87H and 59H will close CHPCON register write attribute. The W78E65 achieves all in-system programming operations including enter/exit ISP Mode, program, erase, read ... etc, during device in the idle mode. Setting the bit CHPCON.0 the device will enter in-system programming mode after a wake-up from idle mode. Because device needs proper time to complete the ISP operations before awaken from idle mode, software may use timer interrupt to control the duration for device wake-up from idle mode. To perform ISP operation for revising contents of AP FLASH EPROM, software located at AP FLASH EPROM setting the CHPCON register then enter idle mode, after awaken from idle mode the device executes the corresponding interrupt service routine in LD FLASH EPROM. Because the device will clear the program counter while switching from AP FLASH EPROM to LD FLASH EPROM, the first execution of RETI instruction in interrupt service routine will jump to 00H at LD FLASH EPROM area. The device offers a software reset for switching back to AP FLASH EPROM while the content of AP FLASH EPROM has been updated completely. Setting CHPCON register bit 0, 1 and 7 to logic-1 will result a software reset to reset the CPU. The software reset serves as a external reset. This insystem programming feature makes the job easy and efficient in which the application needs to update firmware frequently. In some applications, the in-system programming feature make it possible to easily update the system firmware without opening the chassis.

# SFRAH, SFRAL: The objective address of on-chip ROM in the in-system programming mode. SFRAH contains the high-order byte of address, SFRAL contains the low-order byte of address.

**SFRFD:** The programming data for on-chip ROM in programming mode.

SFRCN: The control byte	of on-chip ROM	programming mode.

BIT	NAME	FUNCTION
7	-	Reserve.
On		On-chip ROM bank select for in-system programming.
6	WFWIN	= 0: 64K bytes ROM bank is selected as destination for re-programming.
		= 1: 4K bytes ROM bank is selected as destination for re-programming.
5	OEN	ROM output enable.
4	CEN	ROM chip enable.
3, 2, 1, 0	CTRL[3:0]	The flash control signals

SFRCN	(C7)
-------	------



						1
MODE	WFWIN	CTRL<3:0>	OEN	CEN	SFRAH, SFRAL	SFRFD
Erase 64KB AP FLASH EPROM	0	0010	1	0	Х	х
Program 64KB AP FLASH EPROM	0	0001	1	0	Address in	Data in
Read 64KB AP FLASH EPROM	0	0000	0	0	Address in	Data out
Erase 4KB LD FLASH EPROM	1	0010	1	0	х	х
Program 4KB LD FLASH EPROM	1	0001	1	0	Address in	Data in
Read 4KB LD FLASH EPROM	1	0000	0	0	Address in	Data out

# 6.9.1 In-System Programming Control Register (CHPCON)

### CHPCON (BFH)

BIT	NAME	FUNCTION		
7	SWRESET	When this bit is set to 1, and both FBOOTSL and FPROGEN are set to 1. I will enforce microcontroller reset to initial condition just like power on reset.		
6	-	Reserve.		
5	LD/AP	This bit is read only. 1: CPU is running LD FLASH EPROM program. 0: CPU is running AP FLASH EPROM program.		
4 ENAUXRAM		1: Enable on-chip AUX-RAM.		
		0: Disable the on-chip AUX-RAM		
3	1	Must be 1		
2	-	Reserve.		
1	FBOOTSL	When this bit is set to 1, and both SWRESET and FPROGEN are set to 1. It will enforce microcontroller reset to initial condition just like power on reset.		
0	FPROGEN	When this bit is set to 1, and both SWRESET and FBOOTSL are set to 1. It will enforce microcontroller reset to initial condition just like power on reset.		

This register is protected by CHPENR register. Please write as below procedures while you would like to write CHPCON register.

Mov CHPENR, #87h

Mov CHPENR, #59h

Anl CHPCON, #EFh; Disable AUX-RAM

Mov CHPENR, #0h



### 6.10 Software Reset

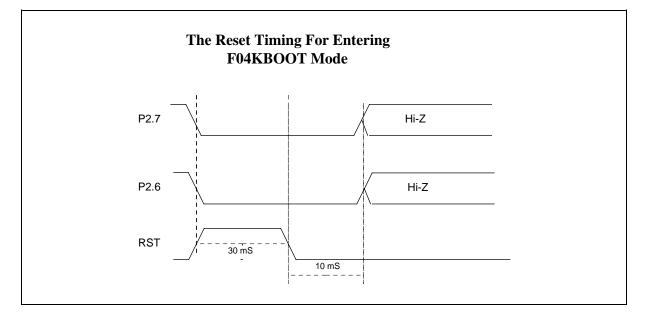
Set CHPCON = 0X83, timer and enter IDLE mode. CPU will reset and restart from APFLASH after time out.

# 6.11 H/W Reboot Mode (Boot from LD FLASH EPROM)

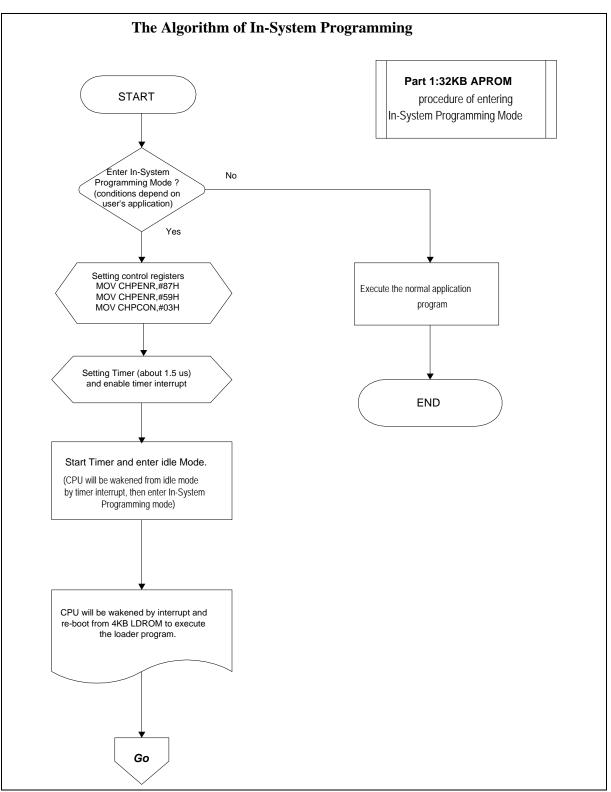
By default, the W78E65 boots from AP FLASH EPROM program after a power on reset. On some occasions, user can force the W78E65 to boot from the LD FLASH EPROM program via following settings. The possible situation that you need to enter H/W REBOOT mode when the AP FLASH EPROM program can not run properly and device can not jump back to LD FLASH EPROM to execute in-system programming function. Then you can use this H/W REBOOT mode to force the W78E65 jumps to LD FLASH EPROM and executes in-system programming procedure. When you design your system, you may reserve the pins P2.6, P2.7 to switches or jumpers. For example in a CD-ROM system, you can connect the P2.6 and P2.7 to PLAY and EJECT buttons on the panel. When the AP FLASH EPROM program fails to execute the normal application program. User can press both two buttons at the same time and then turn on the power of the personal computer to force the W78E65 to enter the H/W REBOOT mode. After power on of personal computer, you can release both buttons and finish the in-system programming procedure to update the AP FLASH EPROM code. In application system design, user must take care of the P2, P3, ALE, EA and PSEN pin value at reset to prevent from accidentally activating the programming mode or H/W REBOOT mode. It is necessary to add 10K resistor on these P2.6, P2.7 and P4.3 pins.

#### H/W Reboot Mode

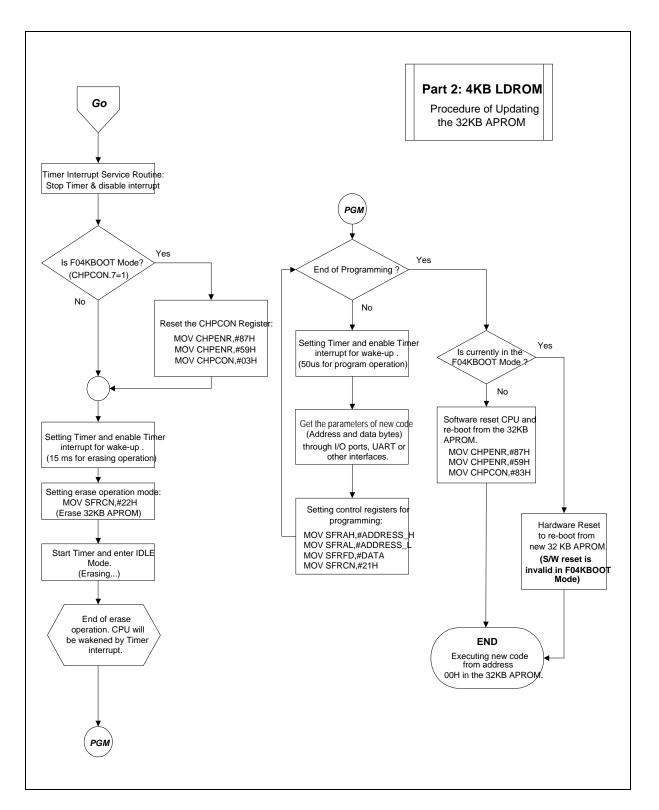
P4.3	P4.3 P2.7 P2.6		MODE
Х	L	L	REBOOT
L	Х	Х	REBOOT









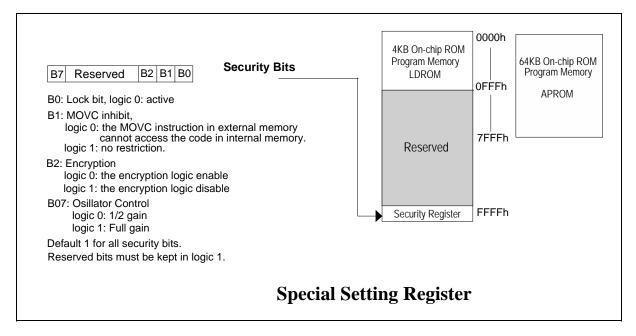




# 6.12 Security

During the on-chip ROM programming mode, the ROM can be programmed and verified repeatedly. Until the code inside the ROM is confirmed OK, the code can be protected. The protection of ROM and those operations on it are described below.

The W78E65 has a Security Register that can be accessed in programming mode. Those bits of the Security Registers can not be changed once they have been programmed from high to low. They can only be reset through erase-all operation. The Security Register is located at the 0FFFFH of the LD FLASH EPROM space.



#### Lock bit

This bit is used to protect the customer's program code in the W78E65. It may be set after the programmer finishes the programming and verifies sequence. Once this bit is set to logic 0, both the ROM data and Security Register can not be accessed again.

#### **MOVC** Inhibit

This bit is used to restrict the accessible region of the MOVC instruction. It can prevent the MOVC instruction in external program memory from reading the internal program code. When this bit is set to logic 0, a MOVC instruction in external program memory space will be able to access code only in the external memory, not in the internal memory. A MOVC instruction in internal program memory space will always be able to access the ROM data in both internal and external memory. If this bit is logic 1, there are no restrictions on the MOVC instruction.

#### Encryption

This bit is used to enable/disable the encryption logic for code protection. Once encryption feature is enabled, the data presented on port 0 will be encoded via encryption logic. Only whole chip erase will reset this bit.



### **Oscillator Control**

W78E65/E516 allow user to diminish the gain of on-chip oscillator amplifier by using programmer to set the bit B7 of security register. Once B7 is set to 0, a half of gain will be decreased. Care must be taken if user attempts to diminish the gain of oscillator amplifier, reducing a half of gain may improperly affect the external crystal operation at high frequency above 24 MHz. The value of R and C1, C2 may need some adjustment while running at lower gain.

# 7. ELETRICAL CHARACTERISTICS

### 7.1 Absolute Maximum Ratings

PARAMETER	SYMBOL	MIN.	MAX.	UNIT
DC Power Supply	$V_{DD} - V_{SS}$	-0.3	+6.0	V
Input Voltage	V <sub>IN</sub>	V <sub>SS</sub> -0.3	V <sub>DD</sub> +0.3	V
Operating Temperature	T <sub>A</sub>	0	70	°C
Storage Temperature	T <sub>ST</sub>	-55	+150	°C

Note: Exposure to conditions beyond those listed under Absolute Maximum Ratings may adversely affect the life and reliability of the device.

# 7.2 DC Characteristics

(V\_DD - V\_SS= 5V  $\pm 10\%,$  T\_A= 25°C, Fosc = 20MHz, unless otherwise specified.)

SYMBOL	PARAMETER	SF	ECIFICAT	ION	TEST CONDITIONS
OTMBOL		MIN.	MAX.	UNIT	
V <sub>DD</sub>	Operating Voltage	4.5	5.5	V	$RST = 1, P0 = V_{DD}$
	Operating Current		20	mA	No load
I <sub>DD</sub>	Operating Current	-	20	ША	$V_{DD} = 5.5V$
	Idle Current		6	m۸	Idle mode
I <sub>IDLE</sub>		-	0	mA	$V_{DD} = 5.5V$
1	Power Down Current	-	10	μA	Power-down mode
PWDN					$V_{DD} = 5.5V$
	Input Current	-50	110	A	$V_{DD} = 5.5V$
I <sub>IN1</sub>	P1, P2, P3, P4	-50	+10 μA	μΑ	$V_{IN} = 0V \text{ or } V_{DD}$
	Input Current	10	+300	0 μΑ	$V_{DD} = 5.5V$
I <sub>IN2</sub>	RST	-10			0 <v<sub>IN<v<sub>DD</v<sub></v<sub>
	Input Leakage Current	10	. 10	μΑ	V <sub>DD</sub> = 5.5V
I <sub>LK</sub>	P0, ĒĀ	-10	+10		0V <v<sub>IN<v<sub>DD</v<sub></v<sub>
I <sub>TL</sub> <sup>[*4]</sup>	Logic 1 to 0 Transition Current	500		μΑ	V <sub>DD</sub> = 5.5V
ITL, ,	P1, P2, P3, P4	-500	-		V <sub>IN</sub> =2.0V



DC Characteristics, continued

SYMBOL	PARAMETER	S	SPECIFICATIO	TEST CONDITIONS	
STMBUL		MIN.	MAX.	UNIT	TEST CONDITIONS
N/	Input Low Voltage	0		v	
V <sub>IL1</sub>	P0, P1, P2, P3, P4, EA	0	0.8	v	$V_{DD} = 4.5V$
V <sub>IL2</sub>	Input Low Voltage RST	0	0.8	V	V <sub>DD</sub> = 4.5V
V <sub>IL3</sub>	Input Low Voltage XTAL1 <sup>[*4]</sup>	0	0.8	V	V <sub>DD</sub> = 4.5V
V <sub>IH1</sub>	Input High Voltage	2.4	V <sub>DD</sub> +0.2	V	V <sub>DD</sub> = 5.5V
V IH1	P0, P1, P2, P3, P4, EA	2.4	V DD +0.2	v	V <sub>DD</sub> = 3.3 V
V <sub>IH2</sub>	Input High Voltage RST	3.5	V <sub>DD</sub> +0.2	V	V <sub>DD</sub> = 5.5V
V <sub>IH3</sub>	Input High Voltage XTAL1 <sup>[*4]</sup>	3.5	V <sub>DD</sub> +0.2	v	V <sub>DD</sub> = 5.5V
V <sub>OL1</sub>	Output Low Voltage	-	0.45	V	$V_{DD} = 4.5 V$
V OL1	P1, P2, P3, P4				I <sub>OL</sub> = +2 mA
V <sub>OL2</sub>	Output Low Voltage	_	0.45	V	$V_{DD} = 4.5V$
• 0L2	P0, ALE, PSEN <sup>[*3]</sup>		0110		I <sub>OL</sub> = +4 mA
lsk1	Sink current P1, P3, P4	4	12	mA	V <sub>DD</sub> = 4.5V VOL = 0.45V
lal-0	Sink current	40	20	mA	V <sub>DD</sub> = 4.5V
lsk2	P0, P2, ALE, PSEN	10			VOL = 0.45V
V <sub>OH1</sub>	Output High Voltage	2.4	-	V	$V_{DD} = 4.5V$
V OH1	P1, P2, P3, P4	2.4			I <sub>OH</sub> = -100 μA
V <sub>OH2</sub>	Output High Voltage	2.4	_	V	$V_{DD} = 4.5V$
V OH2	P0, ALE, PSEN <sup>[*3]</sup>	2.4	-	v	I <sub>OH</sub> = -400 μA
lsr1	Source current	-120	-250	uA	V <sub>DD</sub> = 4.5V
	P1, P2, P3, P4	-120	-200		VOH = 2.4V
lsr2	Source current	-8	-20	mA	$V_{DD} = 4.5V$
1012	P0, P2, ALE, PSEN		-20	IIIA	VOH = 2.4V

Notes:

\*1. RST pin is a Schmitt trigger input.

\*2. P0, ALE and  $\overrightarrow{PSEN}$  are tested in the external access mode.

\*3. XTAL1 is a CMOS input.

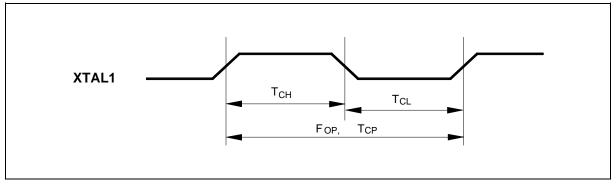
\*4. Pins of P1, P2, P3, P4 can source a transition current when they are being externally driven from 1 to 0.



### 7.3 AC Characteristics

The AC specifications are a function of the particular process used to manufacture the part, the ratings of the I/O buffers, the capacitive load, and the internal routing capacitance. Most of the specifications can be expressed in terms of multiple input clock periods (TCP), and actual parts will usually experience less than a  $\pm 20$  nS variation.

#### **Clock Input Waveform**



PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTES
Operating Speed	F <sub>OP</sub>	0	-	40	MHz	1
Clock Period	T <sub>CP</sub>	41.7	-	-	nS	2
Clock High	Т <sub>сн</sub>	20	-	-	nS	3
Clock Low	T <sub>CL</sub>	20	-	-	nS	3

Notes:

1. The clock may be stopped indefinitely in either state.

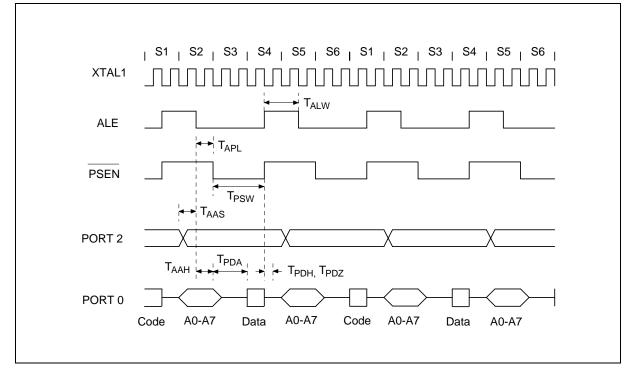
2. The TCP specification is used as a reference in other specifications.

3. There are no duty cycle requirements on the XTAL1 input.



# 8. TIMING WAVEFORMS

# 8.1 Program Fetch Cycle



PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTES
Address Valid to ALE Low	TAAS	1 Тср-∆	-	-	nS	4
Address Hold from ALE Low	Таан	1 Тср-∆	-	-	nS	1, 4
ALE Low to PSEN Low	TAPL	1 Tcp-Δ	-	-	nS	4
PSEN Low to Data Valid	Tpda	-	-	2 TCP	nS	2
Data Hold after PSEN High	Тррн	0	-	1 TCP	nS	3
Data Float after PSEN High	Tpdz	0	-	1 TCP	nS	
ALE Pulse Width	TALW	2 Tcp-Δ	2 TCP	-	nS	4
PSEN Pulse Width	TPSW	З Тср- $\Delta$	3 Тср	-	nS	4

Notes:

1. P0.0-P0.7, P2.0-P2.7 remain stable throughout entire memory cycle.

2. Memory access time is 3  $\ensuremath{\mathsf{TCP}}$  .

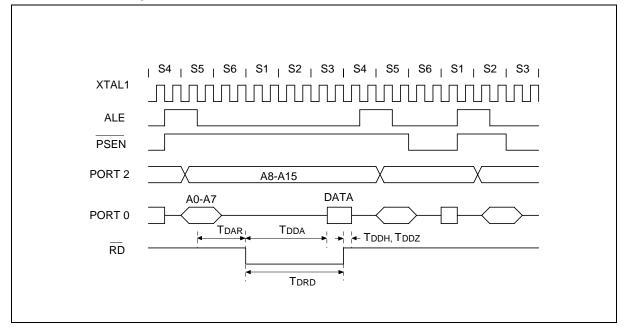
3. Data have been latched internally prior to PSEN going high.

4. " $\Delta$ " (due to buffer driving delay and wire loading) is 20 nS.



#### Timing Waveforms, continued

# 8.2 Data Read Cycle



PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTES
ALE Low to RD Low	T <sub>DAR</sub>	$3  \text{T}_{\text{CP-}}\Delta$	-	$3 T_{CP} + \Delta$	nS	1, 2
RD Low to Data Valid	T <sub>DDA</sub>	-	-	4 T <sub>CP</sub>	nS	1
Data Hold from RD High	T <sub>DDH</sub>	0	-	2 T <sub>CP</sub>	nS	
Data Float from RD High	$T_{DDZ}$	0	-	2 T <sub>CP</sub>	nS	
RD Pulse Width	T <sub>DRD</sub>	$6 T_{CP} \Delta$	6 Т <sub>СР</sub>	-	nS	2

Notes:

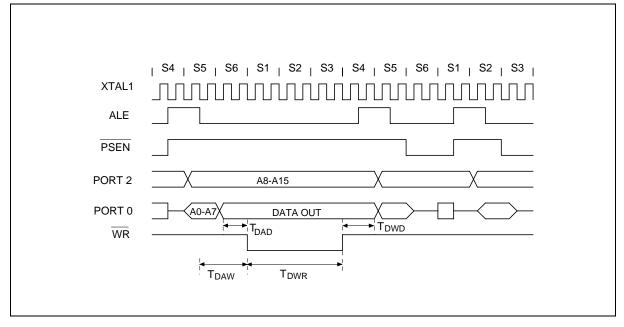
1. Data memory access time is 8 Tcp.

2. " $\Delta$ " (due to buffer driving delay and wire loading) is 20 nS.



Timing Waveforms, continued

### 8.3 Data Write Cycle



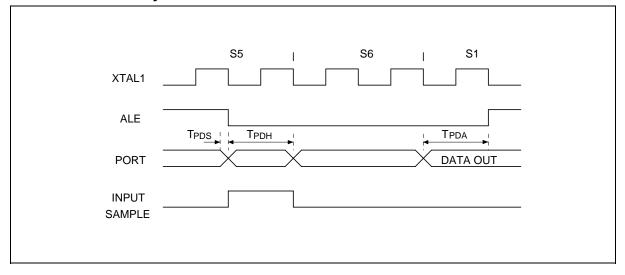
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
ALE Low to WR Low	TDAW	3 Тср-∆	-	3 TCP+ $\Delta$	nS
Data Valid to WR Low	Tdad	1 Тср-∆	-	-	nS
Data Hold from WR High	Towd	1 Тср-∆	-	-	nS
WR Pulse Width	Tdwr	6 Тср-∆	6 Тср	-	nS

Note: " $\Delta$ " (due to buffer driving delay and wire loading) is 20 nS.



Timing Waveforms, continued

### 8.4 Port Access Cycle



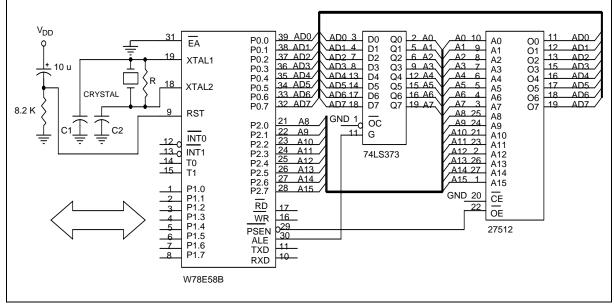
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Port Input Setup to ALE Low	T <sub>PDS</sub>	1 T <sub>CP</sub>	-	-	nS
Port Input Hold from ALE Low	T <sub>PDH</sub>	0	-	-	nS
Port Output to ALE	T <sub>PDA</sub>	1 T <sub>CP</sub>	-	-	nS

Note: Ports are read during S5P2, and output data becomes available at the end of S6P2. The timing data are referenced to ALE, since it provides a convenient reference.



# 9. TYPICAL APPLICATION CIRCUIT

# 9.1 External Program Memory and Crystal



#### Figure A

CRYSTAL	C1	C2	R
6 MHz	47P	47P	-
16 MHz	30P	30P	-
24 MHz	15P	15P	-
32 MHz	10P	10P	6.8K
40 MHz	5P	5P	4.7K

Above table shows the reference values for crystal applications.

Notes:

1. C1, C2, R components refer to Figure A

2. Crystal layout must get close to XTAL1 and XTAL2 pins on user's application board.



Typical Application Circuit, continued

# 9.2 Expanded External Data Memory and Oscillator

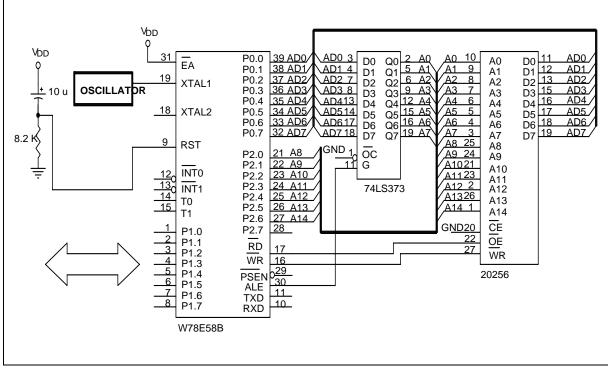
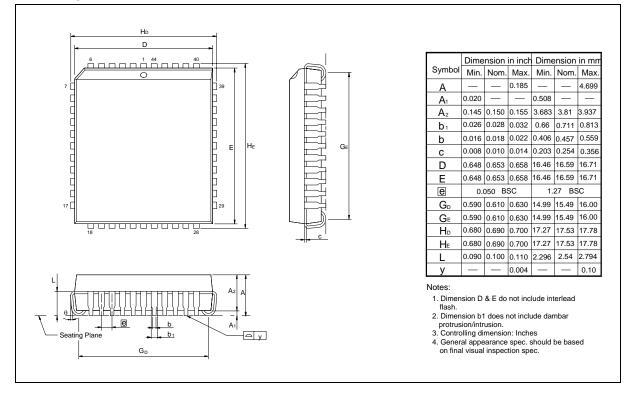


Figure B



# **10. PACKAGE DIMENSIONS**

# 10.1 44-pin PLCC





**11. APPLICATION NOTE** 

### 11.1 In-system Programming Software Examples

This application note illustrates the in-system programmability of the Winbond W78E65 ROM microcontroller. In this example, microcontroller will boot from 64KB AP FLASH EPROM bank and waiting for a key to enter in-system programming mode for re-programming the contents of 64KB AP FLASH EPROM. While entering in-system programming mode, microcontroller executes the loader program in 4KB LD FLASH EPROM bank. The loader program erases the 64KB AP FLASH EPROM then reads the new code data from external SRAM buffer (or through other interfaces) to update the 64KB AP FLASH EPROM.

#### EXAMPLE 1:

\* Example of 64K AP FLASH EPROM program: Program will scan the P1.0. If P1.0 = 0, enters insvstem ;\* programming mode for updating the content of AP FLASH EPROM code else executes the current ROM code. :\* XTAL = 16 MHz \*\*\*\*\* .chip 8052 .RAMCHK OFF .symbols CHPCON EQU BFH CHPENR EQU F6H SFRAL EQU C4H SFRAH EQU C5H SFRFD EQU C6H SFRCN EQU C7H ORG 0H : JUMP TO MAIN PROGRAM LJMP 100H \* \*\*\*\*\* \*\*\*\*\*\*\*\* TIMER0 SERVICE VECTOR ORG = 000BH ORG 00BH TR0 ; TR0 = 0, STOP TIMER0 CLR MOV TL0. R6 MOV TH0, R7 RETI \*\*\*\*\* 64K AP FLASH EPROM MAIN PROGRAM ORG100H MAIN\_64K: MOV A. P1 : SCAN P1.0 ANL A. #01H CJNE A, #01H, PROGRAM\_64K; IF P1.0 = 0, ENTER IN-SYSTEM PROGRAMMING MODE JMP NORMAL\_MODE PROGRAM\_64K: MOV CHPENR, #87H ; CHPENR = 87H, CHPCON REGISTER WRTE ENABLE



MOV CHPENR, #59H MOV CHPCON, #03H MOV TCON, #00H MOV IP, #00H MOV IE, #82H MOV R6, #F0H MOV R6, #FFH MOV TL0, R6 MOV TH0, R7	; CHPENR = 59H, CHPCON REGISTER WRITE ENABLE ; CHPCON = 03H, ENTER IN-SYSTEM PROGRAMMING MODE ; TR = 0 TIMER0 STOP ; IP = 00H ; TIMER0 INTERRUPT ENABLE FOR WAKE-UP FROM IDLE MODE ; TL0 = F0H ; TH0 = FFH
MOV TMOD, #01H MOV TCON, #10H MOV PCON, #01H	; TMOD = 01H, SET TIMER0 A 16-BIT TIMER ; TCON = 10H, TR0 = 1, GO ; ENTER IDLE MODE FOR LAUNCHING THE IN-SYSTEM
	; PROGRAMMING

\* Normal mode 64KB AP FLASH EPROM program: depending user's application

# NORMAL\_MODE:

; User's application program

- ·
- •

#### **EXAMPLE 2:**

Example of 4 KB LD FLASH EPROM program: This loader program will erase the 64KB AP FLASH EPROM first, then reads the new ;\* code from external SRAM and program them into 32 KB AP FLASH EPROM bank. XTAL = 16 MHz

.chip 8052 .RAMCHK OFF .symbols

CHPCON	EQU	BFH	
CHPENR	EQU	F6H	
SFRAL	EQU	C4H	
SFRAH	EQU	C5H	
SFRFD	EQU	C6H	
SFRCN	EQU	C7H	
ORG	000H		
LJMP	100H		

; JUMP TO MAIN PROGRAM

```
;* 1. TIMER0 SERVICE VECTOR ORG = 0BH
```

ORG 000BH CLR TR0 ; TR0 = 0, STOP TIMER0 MOV TL0, R6 MOV TH0, R7 RETI ;\* 4KB LD FLASH EPROM MAIN PROGRAM



ORG 100H MAIN_4K:	
MOV SP, #C0H MOV CHPENR, #87H MOV CHPENR, #59H MOV CHPCON, #03H MOV CHPENR, #00H	; CHPENR = 87H, CHPCON WRITE ENABLE. ; CHPENR = 59H, CHPCON WRITE ENABLE. ; CHPCON = 03H, ENABLE IN-SYSTEM PROGRAMMING. ; DISABLE CHPCON WRITE ATTRIBUTE
MOV TMOD, #01H MOV IP, #00H MOV IE, #82H MOV R6, #F0H MOV R7, #FFH MOV TL0, R6 MOV TH0, R7	; TCON = 00H, TR = 0 TIMER0 STOP ; TMOD = 01H, SET TIMER0 A 16BIT TIMER ; IP = 00H ; IE = 82H, TIMER0 INTERRUPT ENABLED ; TCON = 10H, TR0 = 1, GO ; ENTER IDLE MODE
	,
UPDATE_64K: MOV TCON, #00H MOV IP, #00H MOV IE, #82H MOV TMOD, #01H MOV R6, #E0H DEPENDING MOV R7, #B1H MOV TL0, R6 MOV TH0, R7	; TCON = 00H, TR = 0 TIM0 STOP ; IP = 00H ; IE = 82H, TIMER0 INTERRUPT ENABLED ; TMOD = 01H, MODE1 ; SET WAKE-UP TIME FOR ERASE OPERATION, ABOUT 15 mS. ; ON USER'S SYSTEM CLOCK RATE.
ERASE_P_4K:	
	; SFRCN (C7H) = 22H ERASE 64K ; TCON = 10H, TR0 = 1, GO ; ENTER IDLE MODE (FOR ERASE OPERATION)
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;* BLANK CHECK	*******
, MOV SFRCN, #0H MOV SFRAH, #0H MOV R6, #FEH MOV R7, #FFH MOV TL0, R6 MOV TH0, R7	; READ 64KB AP FLASH EPROM MODE ; START ADDRESS = 0H ; SET TIMER FOR READ OPERATION, ABOUT 1.5 $\mu$ S.
BLANK_CHECK_LOOP:	
SETB TR0 MOV PCON, #01H MOV A, SFRFD CJNE A, #FFH, BLANK_CHEC INC SFRAL MOV A, SFRAL JNZ BLANK_CHECK_LOOP INC SFRAH	; ENABLE TIMER 0 ; ENTER IDLE MODE ; READ ONE BYTE K_ERROR ; NEXT ADDRESS



	MOV A, SFRAH CJNE A, #80H, BLANK_CHECK_LOOP ;END ADDRESS = 7FFFH JMP PROGRAM_64KROM					
BLANK_CHECK_ERROR: MOV P1, #F0H MOV P3, #F0H JMP \$						
;*RE-PROGRAMMING 64KB A	P FLASH EPROM BANK					
, PROGRAM_64KROM:						
MOV R1, #00H ; T MOV DPTR, #0H ; E MOV SFRAH, R1 ; S MOV SFRCN, #21H ; S	THE ADDRESS OF NEW ROM CODE TARGET LOW BYTE ADDRESS TARGET HIGH BYTE ADDRESS EXTERNAL SRAM BUFFER ADDRESS SFRAH, TARGET HIGH ADDRESS SFRCN (C7H) = 21 (PROGRAM 64K) SET TIMER FOR PROGRAMMING, ABOUT 50 μS.					
PROG_D_64K:						
MOVX A, @DPTR MOV SFRFD, A MOV TCON, #10H	; SFRAL (C4H) = LOW BYTE ADDRESS ; READ DATA FROM EXTERNAL SRAM BUFFER. BY ACCORDING USER? ; CIRCUIT, USER MUST MODIFY THIS INSTRUCTION TO FETCH CODE ; SFRFD (C6H) = DATA IN ; TCON = 10H, TR0 = 1, GO ; ENTER IDLE MODE (PRORGAMMING)					
CJNE R2, #0H, PROG_D INC R1 MOV SFRAH, R1 CJNE R1, #80H, PROG_I						
.****	******					
, ; * VERIFY 64KB AP FLASH EP	ROM BANK					
, MOV R4, #03H MOV R6, #FEH MOV R7, #FFH MOV TL0, R6 MOV TH0, R7	; ERROR COUNTER ; SET TIMER FOR READ VERIFY, ABOUT 1.5 $\mu S.$					
MOV DPTR, #0H MOV R2, #0H MOV R1, #0H MOV SFRAH, R1 MOV SFRCN, #00H	; The start address of sample code ; Target low byte address ; Target high byte address ; SFRAH, Target high address ; SFRCN = 00 (Read ROM CODE)					
READ_VERIFY_64K: MOV SFRAL, R2	; SFRAL (C4H) = LOW ADDRESS					



MOV TCON, #10H ; TCON = 10H, TR0 = 1, GO MOV PCON, #01H INC R2 MOVX A, @DPTR INC DPTR CJNE A, SFRFD, ERROR\_64K CJNE R2, #0H, READ\_VERIFY\_64K INC R1 MOV SFRAH, R1 CJNE R1, #80H, READ\_VERIFY\_64K

;\* PROGRAMMING COMPLETLY, SOFTWARE RESET CPU

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MOV CHPENR, #87H	; CHPENR = 87H
MOV CHPENR, #59H	; CHPENR = 59H
MOV CHPCON, #83H	; CHPCON = 83H, SOFTWARE RESET.

ERROR\_64K:

DJNZ R4, UPDATE\_64K ; IF ERROR OCCURS, REPEAT 3 TIMES. ; IN-SYSTEM PROGRAMMING FAIL, USER'S PROCESS TO DEAL WITH IT.

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### **12. REVISION HISTORY**

VERSION	DATE	PAGE	DESCRIPTION
A1	May 14, 2003	-	Initial Issued
A2	Dec. 30, 2004	2	Add Lead Free package
A3	E-14 0005	2	Add Lead Free DIP
AS	Feb. 14, 2005	5	Remove P4.4 ~ P4.7
A4	April 20, 2005	38	Add Important Notice
٨٢	luna 22, 2005	27	Correct operating speed from 20Mhz to 40Mhz
A5	June 22, 2005	32	Add 32M/40Mhz items in the table
A6	Aug. 25, 2005	3, 5	Add Port 0 pull-up resisters information
A7	Jan. 9, 2006	3	Add W78E65F-40 and W78E065A40FL

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